



CYPRESS
SEMICONDUCTOR

CY2148/CY21L48
CY2149/CY21L49

1,024 x 4 Static R/W RAM

Features

- Automated power-down when deselected (2148)
- CMOS for optimum speed/power
- Low power
 - 660 mW (commercial)
 - 770 mW (military)
- 5-volt power supply \pm 10% tolerance both commercial and military
- TTL-compatible inputs and outputs

Functional Description

The CY2148 and CY2149 are high-performance CMOS static RAMs organized as 1024 by 4 bits. Easy memory expansion is provided by an active LOW chip select (\overline{CS}) input and three-state outputs. The CY2148 and CY2149 are identical except that the CY2148 includes an automatic (\overline{CS}) power-down feature. The CY2148 remains in a low-power mode as long as the device remains deselected, i.e., (\overline{CS}) is HIGH, thus reducing the average power requirements of the device. The chip select (\overline{CS}) of the CY2149 does not affect the power dissipation of the device.

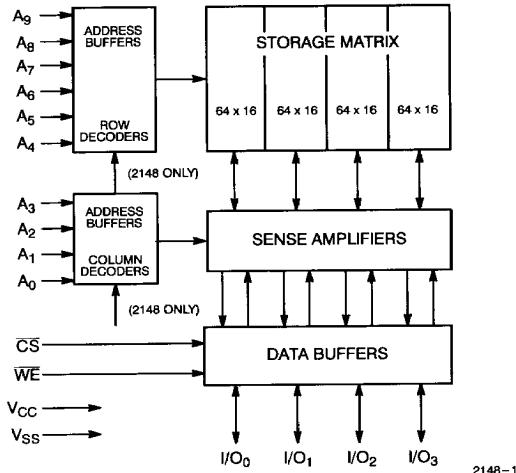
An active LOW write enable signal (\overline{WE}) controls the writing/reading operation of the memory. When the chip select (\overline{CS})

and write enable (\overline{WE}) inputs are both LOW, data on the four data input/output pins (I/O_0 through I/O_3) is written into the memory location addressed by the address present on the address pins (A_0 through A_9).

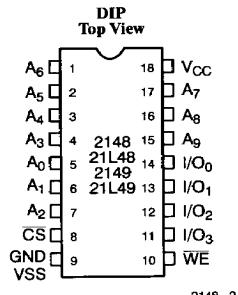
Reading the device is accomplished by selecting the device, (\overline{CS}) active LOW, while (\overline{WE}) remains inactive or HIGH. Under these conditions, the contents of the location addressed by the information on address pins (A_0 through A_9) is present on the four data input/output pins (I/O_0 through I/O_3).

The input/output pins (I/O_0 through I/O_3) remain in a high-impedance state unless the chip is selected and write enable (\overline{WE}) is HIGH.

Logic Block Diagram



Pin Configuration



Selection Guide (For higher performance and lower power refer to the CY7C148/9 data sheet)

| | | 2148-35 2149-35 | 21L48-35 21L49-35 | 2148-45 2149-45 | 21L48-45 21L49-45 | 2148-55 2149-55 | 21L48-55 21L49-55 |
|--------------------------------|------------|--------------------|----------------------|--------------------|----------------------|--------------------|----------------------|
| Maximum Access Time (ns) | | 35 | 35 | 45 | 45 | 55 | 55 |
| Maximum Operating Current (mA) | Commercial | 140 | 120 | 140 | 120 | 140 | 120 |
| | Military | | | 140 | | 140 | |



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

| | |
|----------------------------------------------------------------|-----------------|
| Storage Temperature | -65°C to +150°C |
| Ambient Temperature with Power Applied | -55°C to +125°C |
| Supply Voltage to Ground Potential (Pin 18 to Pin 9) | -0.5V to +7.0V |
| DC Voltage Applied to Outputs in High Z State | -0.5V to +7.0V |

DC Input Voltage - 3.0V to + 7.0V
Output Current into Outputs (Low) 20 mA

| Range | Ambient Temperature | V _{CC} |
|-------------------------|---------------------|-----------------|
| Commercial | 0°C to + 70°C | 5V ± 10% |
| Military ^[1] | - 55°C to + 125°C | 5V ± 10% |

Electrical Characteristics Over the Operating Range^[2]

| Parameters | Description | Test Conditions | 2148 2149 | | 21L48 21L49 | | Units | |
|-----------------|---------------------------------------------|-------------------------------------------------------------|----------------------------------|------|----------------|------|-------|----|
| | | | Min. | Max. | Min. | Max. | | |
| I _{OH} | Output HIGH Current | V _{CC} = Min., V _{OH} = -0.4 mA | 2.4 | | 2.4 | | mA | |
| I _{OL} | Output LOW Current | V _{CC} = Min., V _{OL} = 8.0 mA | | 0.4 | | 0.4 | mA | |
| V _{IH} | Input HIGH Voltage | | 2.0 | 6.0 | 2.0 | 6.0 | V | |
| V _{IL} | Input LOW Voltage | | -3.0 | 0.8 | -3.0 | 0.8 | V | |
| I _{IX} | Input Load Current | V _{SS} ≤ V _I ≤ V _{CC} | -10 | +10 | -10 | +10 | μA | |
| I _{OZ} | Output Leakage Current | GND ≤ V _O ≤ V _{OH} , Output Disabled | T _A = 0°C to +125°C | -50 | +50 | -50 | +50 | μA |
| I _{CC} | V _{CC} Operating Supply Current | Max. V _{CC} , CS ≤ V _{IL} Output Open | T _A = 0°C to +70°C | | 140 | | 120 | mA |
| | | | T _A = -55°C to +125°C | | 140 | | | |
| I _{SB} | Automatic CS Power-Down Current | Max. V _{CC} , CS ≤ V _{IL} (2148 only) | T _A = 0°C to +70°C | | 30 | | 20 | mA |
| | | | T _A = -55°C to +125°C | | 30 | | | |
| I _{PO} | Peak Power-On Current ^[3] | Max. V _{CC} , CS ≤ V _{IL} (2148 only) | T _A = 0°C to +70°C | | 50 | | 30 | mA |
| | | | T _A = -55°C to +125°C | | 50 | | | |
| I _{OS} | Output Short Circuit Current ^[4] | GND ≤ V _O ≤ V _{CC} | T _A = 0°C to +70°C | | ±275 | | ±275 | mA |
| | | | T _A = -55°C to +125°C | | ±350 | | | |

Capacitance^[5]

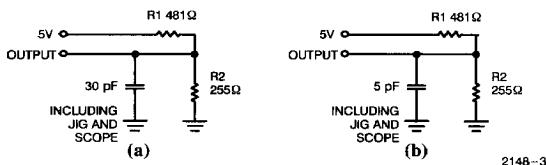
| Parameters | Description | Test Conditions | Max. | Units |
|------------|-------------------|-----------------------------------------------------------|------|-------|
| C_{IN} | InputCapacitance | $T_A = 25^\circ C, f = 1 \text{ MHz},$ $V_{CC} = 5.0V$ | 8 | pF |
| C_{OUT} | OutputCapacitance | | 8 | pF |

Notes:

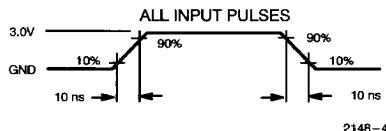
- Notes:**

 1. T_A is the "instant on" case temperature.
 2. See the last page of this specification for Group A subgroup testing information.
 3. A pull-up resistor to V_{CC} on the \overline{CS} input is required to keep the device deselected during V_{CC} power up. Otherwise, current will exceed values give (CY2148 only).
 4. For test purposes, not more than 1 output at a time should be shorted. Short circuit test duration should not exceed 30 seconds.
 5. Tested initially and after any design or process changes that may affect these parameters.

AC Test Loads and Waveforms



Equivalent to: THEVENIN EQUIVALENT



214B-4

Switching Characteristics Over the Operating Range^[2]

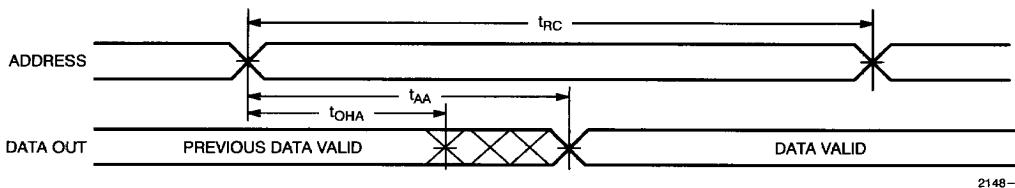
| Parameters | Description | 2148-35 2149-35 | | 2148-45 2149-45 | | 2148-55 2149-55 | | Units |
|----------------------------------|-------------------------------------------------------------|--------------------|------|--------------------|------|--------------------|------|-------|
| | | Min. | Max. | Min. | Max. | Min. | Max. | |
| READ CYCLE | | | | | | | | |
| t _{RC} | Address Valid to Address Do Not Care Time (Read Cycle Time) | 35 | | 45 | | 55 | | ns |
| t _{AA} | Address Valid to Data Out Valid Delay (Address Access Time) | | 35 | | 45 | | 55 | ns |
| t _{ACSI} ^[6] | Chip Select LOW to Data Out Valid (CY2148 only) | | 35 | | 45 | | 55 | ns |
| t _{ACS2} ^[7] | | | 45 | | 55 | | 65 | ns |
| t _{ACS} | Chip Select LOW to Data Out Valid (CY2149 only) | | 15 | | 20 | | 25 | ns |
| t _{LZ} ^[8] | Chip Select LOW to Data Out Valid | 2148 | 10 | | 10 | | 10 | ns |
| | | 2149 | 5 | | 5 | | 5 | |
| t _{HZ} ^[8] | Chp Select HIGH to Data Out Off | 0 | 20 | 0 | 20 | 0 | 20 | ns |
| t _{OH} | Address Unknown to Data Out Unknown Time | 0 | | 5 | | 5 | | ns |
| t _{PD} | Chip Select HIGH to Power-Down Delay | 2148 | | 30 | | 30 | | ns |
| t _{PU} | Chip Select LOW to Power-Up Delay | 2149 | 0 | | 0 | | 0 | ns |
| WRITE CYCLE | | | | | | | | |
| t _{WC} | Address Valid to Address Do Not Care (Write Cycle Time) | 35 | | 45 | | 55 | | ns |
| t _{WP} ^[9] | Write Enable LOW to Write Enable HIGH | 30 | | 35 | | 40 | | ns |
| t _{WR} | Address Hold from Write End | 5 | | 5 | | 5 | | ns |
| t _{WZ} ^[8] | Write Enable LOW to Output in High Z | 0 | 10 | 0 | 15 | 0 | 20 | ns |
| t _{DW} | Data-In Valid to Write Enable HIGH | 20 | | 20 | | 20 | | ns |
| t _{DH} | Data Hold Time | 0 | | 0 | | 0 | | ns |
| t _{AS} | Address Valid to Write Enable LOW | 0 | | 0 | | 0 | | ns |
| t _{CW} ^[9] | Chip Select LOW to Write Enable HIGH | 30 | | 40 | | 50 | | ns |
| t _{OW} ^[8] | Write Enable HIGH to Output in Low Z | 0 | | 0 | | 0 | | ns |
| t _{AW} | Address Valid to End of Write | 30 | | 35 | | 50 | | ns |

Notes:

6. Chip deselected greater than 55 ns prior to selection.
7. Chip deselected less than 55 ns prior to selection.
8. At any given temperature and voltage condition, t_{HZ} is less than t_{LZ} for all devices. Transition is measured $\pm 500\text{ mV}$ from steady state voltage with specified loading in part (b) of AC Test Loads.
9. The internal write time of the memory is defined by the overlap of CS LOW and WE LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.

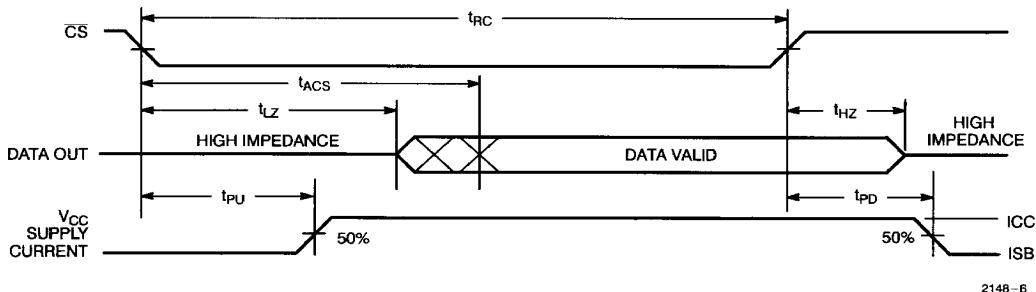
Switching Waveforms

Read Cycle No. 1^[10, 11]



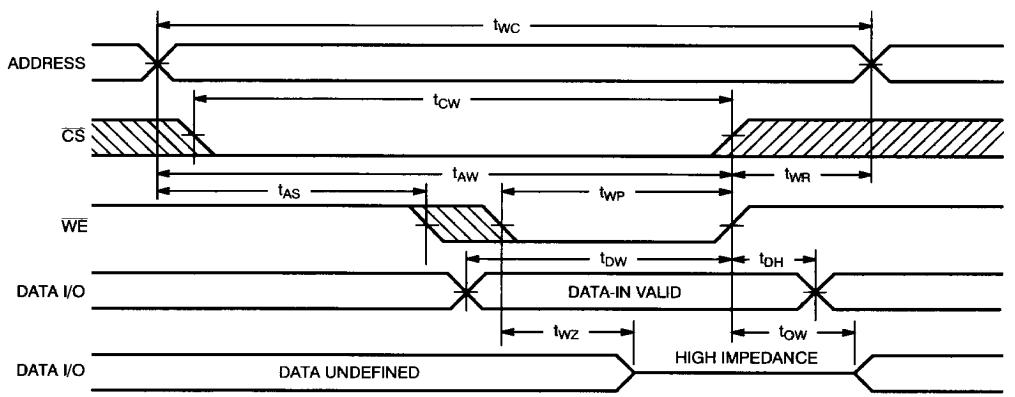
2148-5

Read Cycle No. 2^[10, 12]



2148-6

Write Cycle No. 1 (\overline{WE} Controlled)



2148-7

Notes:

10. \overline{WE} is HIGH for read cycle.
11. Device is continuously selected, $CS = V_{IL}$.
12. Address valid prior to or coincident with CS transition LOW.
13. If CS goes HIGH simultaneously with \overline{WE} HIGH, the output remains in a high-impedance state.

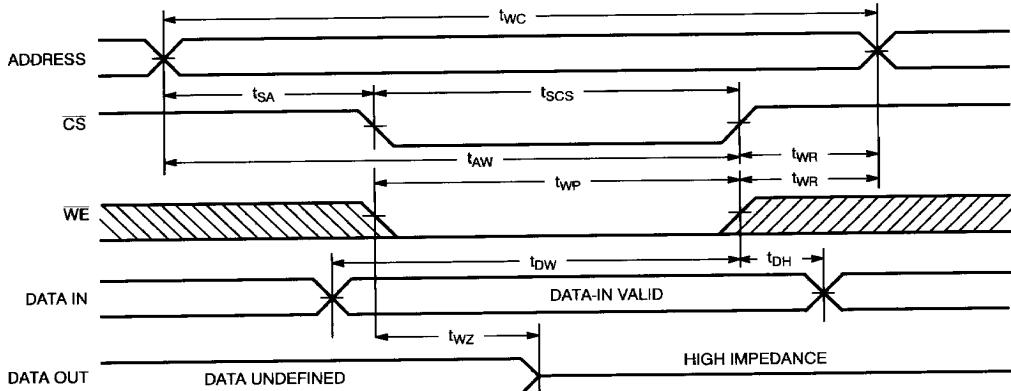
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Switching Waveforms (continued)

Write Cycle No. 2 (CS Controlled) [13]



2148-8

Ordering Information

| Speed (ns) | Ordering Code | Package Type | Operating Range |
|---------------|---------------|--------------|-----------------|
| 35 | CY2148-35PC | P3 | Commercial |
| | CY2148-35DC | D4 | |
| 45 | CY2148-45PC | P3 | Commercial |
| | CY2148-45DC | D4 | |
| 55 | CY2148-45DMB | D4 | Military |
| | CY2148-55PC | P3 | Commercial |
| | CY2148-55DC | D4 | |
| 55 | CY2148-55DMB | D4 | Military |

| Speed (ns) | Ordering Code | Package Type | Operating Range |
|---------------|---------------|--------------|-----------------|
| 35 | CY21L48-35PC | P3 | Commercial |
| | CY21L48-35DC | D4 | |
| 45 | CY21L48-45PC | P3 | Commercial |
| | CY21L48-45DC | D4 | |
| 55 | CY21L48-55PC | P3 | Commercial |
| | CY21L48-20DC | D4 | |

| Speed (ns) | Ordering Code | Package Type | Operating Range |
|---------------|---------------|--------------|-----------------|
| 35 | CY21L49-35PC | P3 | Commercial |
| | CY21L49-35DC | D4 | |
| 45 | CY21L49-45PC | P3 | Commercial |
| | CY21L49-45DC | D4 | |
| 55 | CY21L49-55PC | P3 | Commercial |
| | CY21L49-55DC | D4 | |

| Speed (ns) | Ordering Code | Package Type | Operating Range |
|---------------|---------------|--------------|-----------------|
| 35 | CY2149-35PC | P3 | Commercial |
| | CY2149-35DC | D4 | |
| 45 | CY2149-45PC | P3 | Commercial |
| | CY2149-45DC | D4 | |
| 55 | CY2149-45DMB | D4 | Military |
| | CY2149-55PC | P3 | Commercial |
| | CY2149-55DC | D4 | |
| 55 | CY2149-55DMB | D4 | Military |

**MILITARY SPECIFICATIONS
Group A Subgroup Testing**
DC Characteristics

| Parameters | Subgroups |
|---------------------------------|-----------|
| I _{OH} | 1, 2, 3 |
| I _{OL} | 1, 2, 3 |
| V _{IH} | 1, 2, 3 |
| V _{IL} Max. | 1, 2, 3 |
| I _{IX} | 1, 2, 3 |
| I _{OZ} | 1, 2, 3 |
| I _{CC} | 1, 2, 3 |
| I _{SB} ^[14] | 1, 2, 3 |

Switching Characteristics

| Parameters | Subgroups |
|-----------------------------------|-----------------|
| READ CYCLE | |
| t _{RC} | 7, 8, 9, 10, 11 |
| t _{AA} | 7, 8, 9, 10, 11 |
| t _{ACSI} ^[14] | 7, 8, 9, 10, 11 |
| t _{ACS2} ^[14] | 7, 8, 9, 10, 11 |
| t _{ACS} ^[15] | 7, 8, 9, 10, 11 |
| t _{OH} | 7, 8, 9, 10, 11 |
| WRITE CYCLE | |
| t _{WC} | 7, 8, 9, 10, 11 |
| t _{WP} | 7, 8, 9, 10, 11 |
| t _{WR} | 7, 8, 9, 10, 11 |
| t _{DW} | 7, 8, 9, 10, 11 |
| t _{DH} | 7, 8, 9, 10, 11 |
| t _{AS} | 7, 8, 9, 10, 11 |
| t _{AW} | 7, 8, 9, 10, 11 |

Notes:

14. CY2148 only.

15. CY2149 only.

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